DISCRETE SEMICONDUCTORS

DATA SHEET

BYR29 series Rectifier diodes ultrafast

Product specification

September 2018



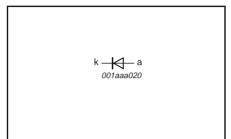
Rectifier diodes ultrafast

BYR29 series

FEATURES

- · Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- · Reverse surge capability
- High thermal cycling performance
- · Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 500 \text{ V/ } 600 \text{ V/ } 700 \text{ V / } 800 \text{ V}$$

$$V_F \le 1.5 \text{ V}$$

$$I_{F(AV)} = 8 \text{ A}$$

$$t_{rr} \le 75 \text{ ns}$$

GENERAL DESCRIPTION

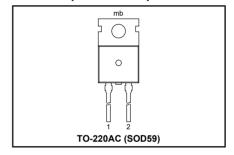
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYR29 series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	cathode		

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT		
V _{RRM} V _{RWM} V _R	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage	BYR29	1 1 1	-500 500 500 500	-600 600 600 600	-700 700 700 700	-800 800 800 800	V V
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$;	-			3		Ā
I _{FRM}	Repetitive peak forward current	$T_{mb} \le 115 ^{\circ}\text{C}$ $t = 25 \mu\text{s}; \delta = 0.5;$ $T_{mb} \le 115 ^{\circ}\text{C}$	-		1	6		A
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied V _{RRM(max)}	-			66 66		A A
T _{stg}	Storage temperature Operating junction temperature	RRM(max)	-40 -			50 50		,C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	2.5	K/W
R _{th j-a}		in free air.	-	60	-	K/W

¹ Neglecting switching and reverse current losses

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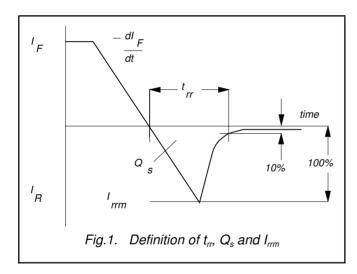
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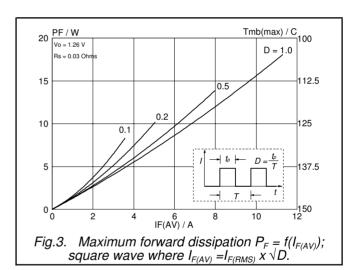
BYR29 series

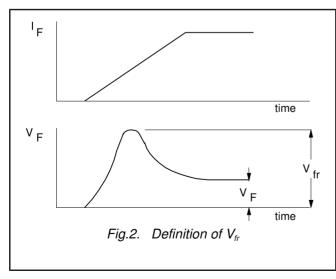
ELECTRICAL CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage	$I_F = 8 \text{ A}; T_j = 150 ^{\circ}\text{C}$	-	1.07	1.50	V
١,	Dovorce ourrent	$I_F = 20 \text{ Å}$	-	1.75	1.95	^
I _R	Reverse current	V _R = V _{RRM} V ₂ - V ₂₂₁ : T ₂ - 100 °C	_	1.0 0.1	10 0.2	μA mA
Q_s	Reverse recovery charge	$V_{R} = V_{RRM}$; $T_{j} = 100 ^{\circ}\text{C}$ $I_{F} = 2 ^{\circ}\text{A to } V_{R} \geq 30 ^{\circ}\text{V}$;	-	150	200	nC
1.	<u> </u>	$dI_F/dt = 20 A/\mu s$				
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$ $dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	60	75	ns
I _{rrm}	Peak reverse recovery current	$I_{\rm F} = 10 \text{ A to } V_{\rm B} \ge 30 \text{ V};$	-	-	6	Α
l.,	Famound was a common alta as a	$dI_F/dt = 50 \text{ A/µs}; T_i = 100 ^{\circ}\text{C}$				\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
V_{fr}	Forward recovery voltage	$I_F = 10 \text{ A}; dI_F/dt = 10 \text{ A}/\mu\text{s}$	-	5.0	-	V







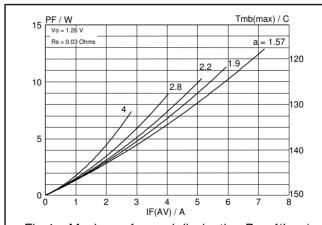
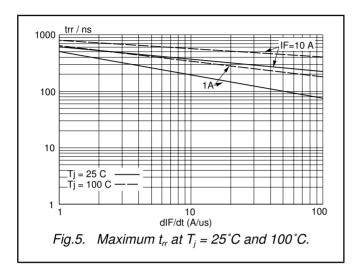


Fig.4. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor = $I_{F(RMS)} / I_{F(AV)}$.

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Rectifier diodes ultrafast

BYR29 series



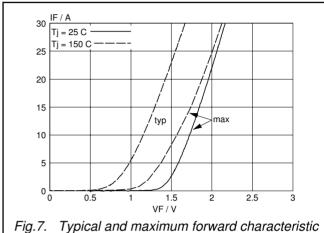
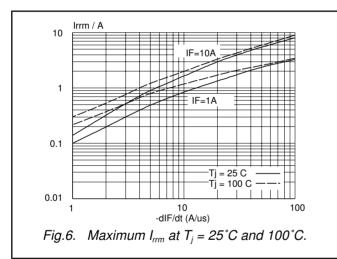
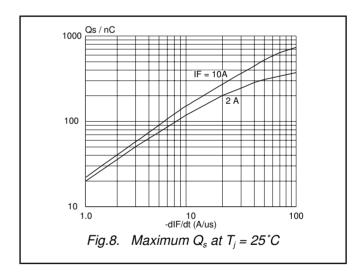
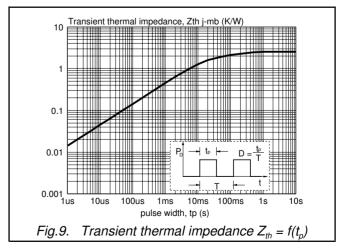


Fig.7. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j



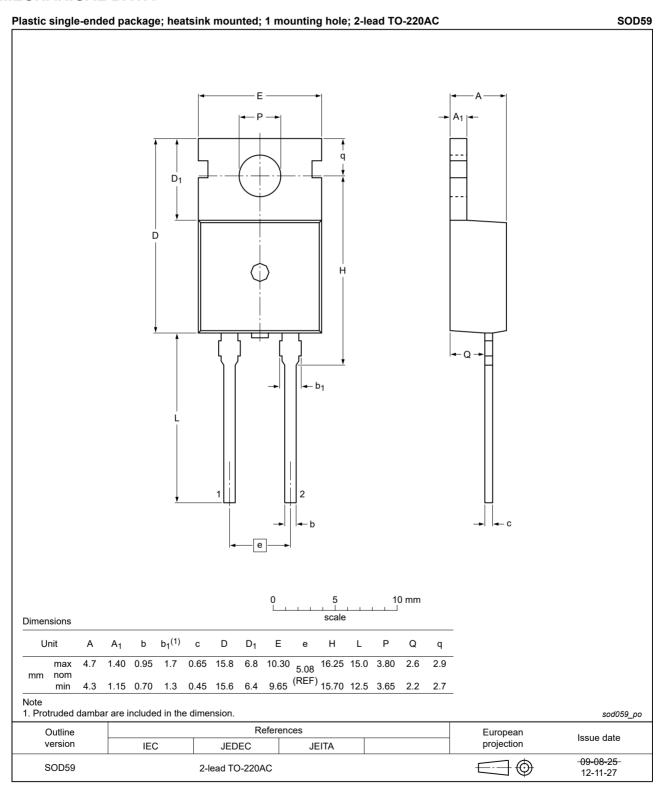




Rectifier diodes ultrafast

BYR29 series

MECHANICAL DATA



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ween-semi.com.

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